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Maße in mm, wenn nicht anders angegeben/Dimensions in mm, unless otherwise specified.

<b>Typ</b> <b>Type</b>	<b>Bestellnummer</b> <b>Ordering Code</b>
SFH 331	Q62702-P1634

## **Wesentliche Merkmale**

- Geeignet für Vapor-Phase Löten und IR-Reflow Löten

## Features

- Suitable for vapor-phase and IR-reflow soldering

**Grenzwerte**  
**Maximum Ratings**

<b>Bezeichnung</b> <b>Description</b>	<b>Symbol</b> <b>Symbol</b>	<b>Wert</b> <b>Value</b>		<b>Einheit</b> <b>Unit</b>
		<b>LED</b>	<b>Transistor</b>	
Betriebstemperatur Operating temperature range	$T_{op}$	– 55 ... + 100	– 55 ... + 100	°C
Lagertemperatur Storage temperature range	$T_{stg}$	– 55 ... + 100	– 55 ... + 100	°C
Sperrsichttemperatur Junction temperature	$T_j$	+ 100	+ 100	°C
Durchlaßstrom (LED) Forward current (LED)	$I_F$	30	–	mA
Kollektorstrom (Transistor) Collector current (Transistor)	$I_C$	–	15	mA
Stoßstrom Surge current $t \leq 10 \mu\text{s}, D = 0.005$	$I_{FM}$	500	75	mA
Sperrspannung (LED) Reverse voltage (LED)	$V_R$	5	–	V
Kollektor-Emitter Spannung (Transistor) Collector-emitter voltage (Transistor)	$V_{CE}$	–	35	V
Verlustleistung Total power dissipation	$P_{tot}$	100	165	mW
Wärmewiderstand Sperrsicht/Umgebung Thermal resistance junction/ambient	$R_{th JA}$	450	450	K/W
Montage auf PC-Board* (Padgröße $\geq 16 \text{ mm}^2$ ) mounting on pcb* (pad size $\geq 16 \text{ mm}^2$ )				
Sperrsicht / Lötstelle junction / soldering joint	$R_{th JS}$	350	–	K/W

\* PC-board: G30/FR4

**Notes**

Die angegebenen Grenzdaten gelten für den Chip, für den sie angegeben sind, unabhängig vom Betriebszustand des anderen.

The stated max. ratings refer to the specified chip regardless of the operating status of the other one.

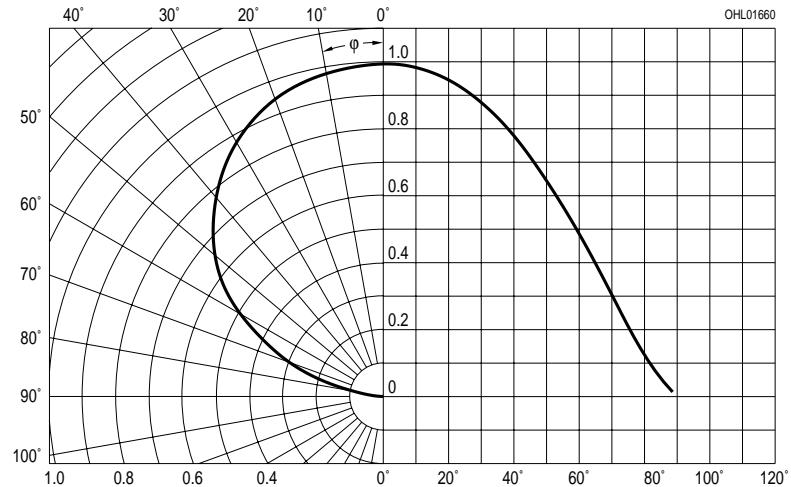
**Kennwerte LED ( $T_A = 25^\circ\text{C}$ )**  
**Characteristics LED**

Bezeichnung Description	Symbol Symbol	Wert Value	Einheit Unit
Wellenlänge des emittierten Lichtes (typ.) Wavelength at peak emission (typ.) $I_F = 10 \text{ mA}$	$\lambda_{\text{peak}}$	635	nm
Dominantwellenlänge (typ.) Dominant wavelength (typ.) $I_F = 10 \text{ mA}$	$\lambda_{\text{dom}}$	628	nm
Spektrale Bandbreite bei 50 % $I_{\text{rel max}}$ (typ.) Spectral bandwidth at 50 % $I_{\text{rel max}}$ (typ.) $I_F = 10 \text{ mA}$	$\Delta\lambda$	45	nm
Abstrahlwinkel bei 50 % $I_V$ (Vollwinkel) Viewing angle at 50 % $I_V$	$2\phi$	120	Grad degr.
Durchlaßspannung (typ.) Forward voltage (max.) $I_F = 10 \text{ mA}$	$V_F$ $V_F$	2.0 2.6	V V
Sperrstrom (typ.) Reverse current (max.) $V_R = 5 \text{ V}$	$I_R$ $I_R$	0.01 10	$\mu\text{A}$ $\mu\text{A}$
Kapazität (typ.) Capacitance $V_R = 0 \text{ V}, f = 1 \text{ MHz}$	$C_0$	12	pF
Schaltzeiten: Switching times: $I_V$ from 10 % to 90 % (typ.) $I_V$ from 90 % to 10 % (typ.) $I_F = 100 \text{ mA}, t_p = 10 \mu\text{s}, R_L = 50 \Omega$	$t_r$ $t_f$	300 150	ns ns
Lichtstärke (Gruppe JK) (typ.) Luminous intensity (group JK) $I_F = 10 \text{ mA}$	$I_V$	6 (4.0 ... 12.5)	mcd

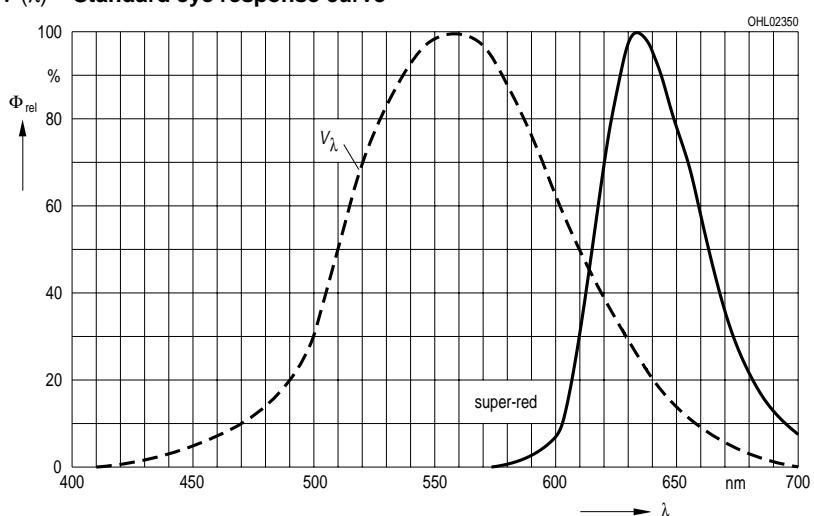
**Kennwerte Fototransistor ( $T_A = 25^\circ\text{C}$ ,  $\lambda = 950 \text{ nm}$ )**  
**Characteristics Phototransistor**

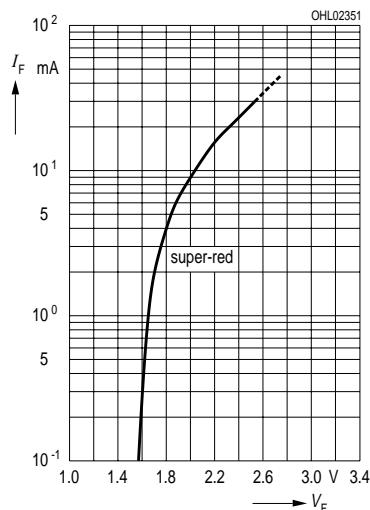
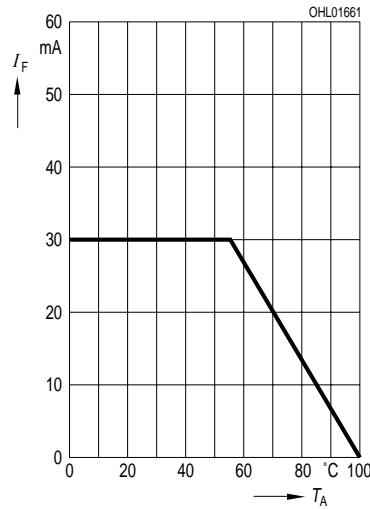
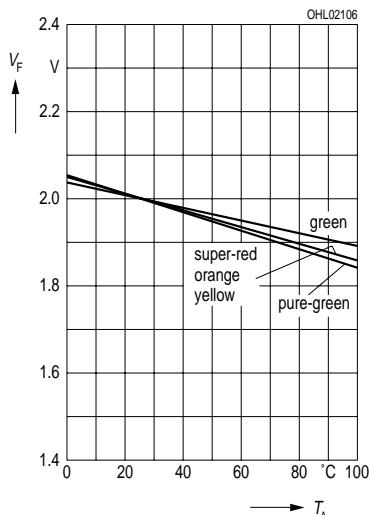
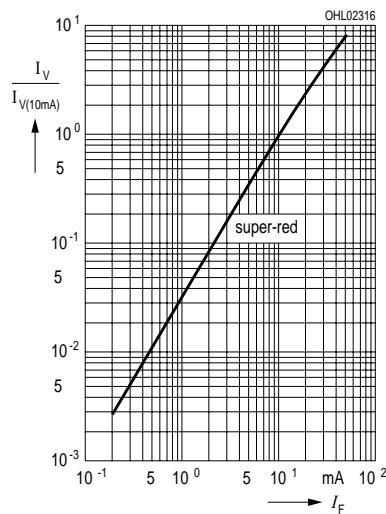
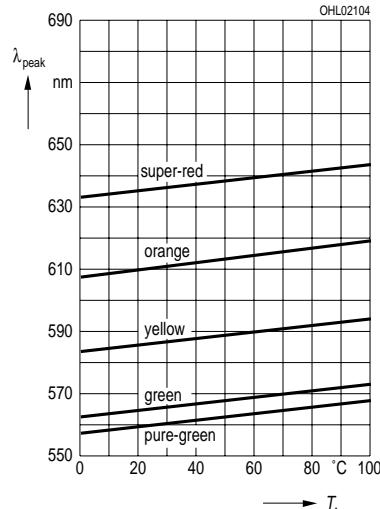
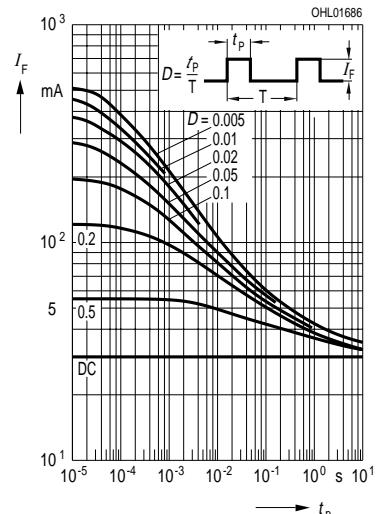
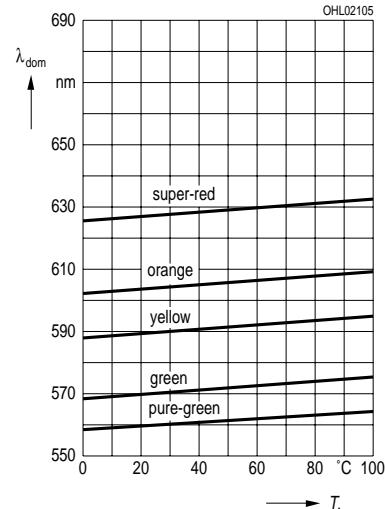
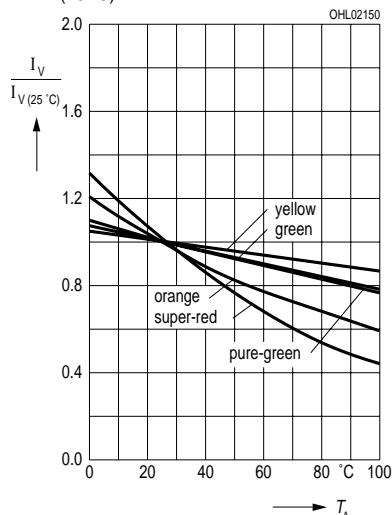
Bezeichnung Description	Symbol Symbol	Wert Value	Einheit Unit
Wellenlänge der max. Fotoempfindlichkeit Wavelength of max. sensitivity	$\lambda_{S \max}$	860	nm
Spektraler Bereich der Fotoempfindlichkeit $S = 10\%$ von $S_{\max}$ Spectral range of sensitivity $S = 10\%$ of $S_{\max}$	$\lambda$	380 ... 1150	nm
Bestrahlungsempfindliche Fläche ( $\varnothing 240 \mu\text{m}$ ) Radiant sensitive area ( $\varnothing 240 \mu\text{m}$ )	A	0.045	$\text{mm}^2$
Abmessung der Chipfläche Dimensions of chip area	$L \times B$	$0.45 \times 0.45$	$\text{mm} \times \text{mm}$
Abstand Chipoberfläche zu Gehäuseoberfläche Distance chip front to case surface	H	0.5 ... 0.7	mm
Halbwinkel Half angle	$\phi$	$\pm 60$	Grad degr.
Kapazität Capacitance $V_{CE} = 0 \text{ V}, f = 1 \text{ MHz}, E = 0$	$C_{CE}$	5.0	pF
Dunkelstrom Dark current $V_{CE} = 25 \text{ V}, E = 0$	$I_{CEO}$	1 ( $\leq 200$ )	nA
Fotostrom Photocurrent $E_e = 0.1 \text{ mW/cm}^2, V_{CE} = 5 \text{ V}$	$I_{PCE}$	$\geq 16$	$\mu\text{A}$
Anstiegszeit/Abfallzeit Rise time/Fall time $I_C = 1 \text{ mA}, V_{CC} = 5 \text{ V}, R_L = 1 \text{ k}\Omega$	$t_r, t_f$	7	$\mu\text{s}$
Kollektor-Emitter-Sättigungsspannung Collector-emitter saturation voltage $I_C = 5 \mu\text{A}, E_e = 0.1 \text{ mW/cm}^2$	$V_{CEsat}$	150	mV

LED Radiation characteristics  $I_{\text{rel}} = f(\phi)$   
Phototransistor Directional characteristics  $S_{\text{rel}} = f(\phi)$

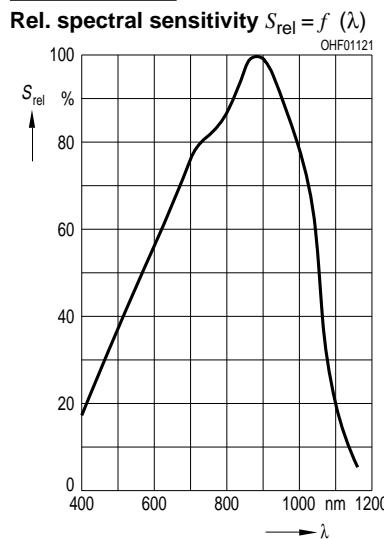


LED Relative spectral emission  $I_{\text{rel}} = f(\lambda)$ ,  $T_A = 25^\circ\text{C}$ ,  $I_F = 20\text{ mA}$   
 $V(\lambda)$  = Standard eye response curve



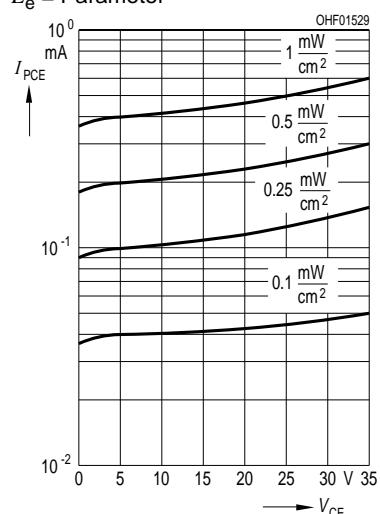
**Forward current  $I_F = f(V_F)$** 
 $T_A = 25^\circ\text{C}$ 

**Max. permissible forward current  $I_F = f(T_A)$** 
 $I_F = f(T_A)$ 

**Forward current  $V_F = f(T_A)$** 
 $I_F = 10 \text{ mA}$ 

**Rel. luminous intensity**
 $I_V / I_{V(10 \text{ mA})} = f(I_F), T_A = 25^\circ\text{C}$ 

**Wavelength at peak emission**
 $\lambda_{\text{peak}} = f(T_A), I_F = 20 \text{ mA}$ 

**Perm. pulse handling capability  $I_F = f(t_p)$** 
 $\text{Duty cycle } D = \text{parameter}, T_A = 25^\circ\text{C}$ 

**Dominant wavelength  $\lambda_{\text{dom}} = f(T_A)$** 
 $I_F = 20 \text{ mA}$ 

**Rel. luminous intensity**
 $I_V / I_{V(25^\circ\text{C})} = f(T_A), I_F = 10 \text{ mA}$ 


## Phototransistor



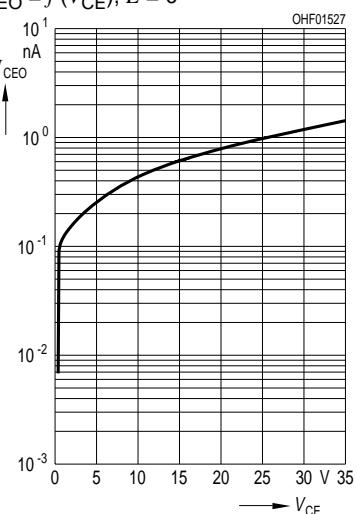
## Photocurrent $I_{\text{PCE}} = f(V_{\text{CE}})$ ,

$E_e = \text{Parameter}$



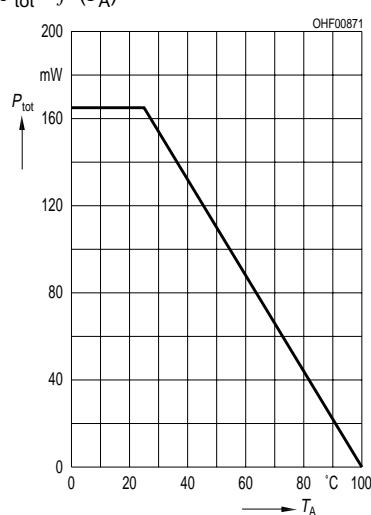
## Dark current

$I_{\text{CEO}} = f(V_{\text{CE}}), E = 0$



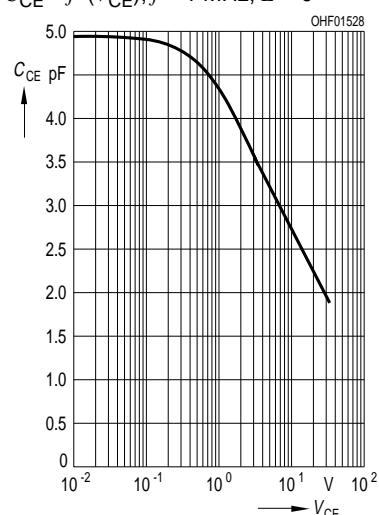
## Total power dissipation

$P_{\text{tot}} = f(T_A)$



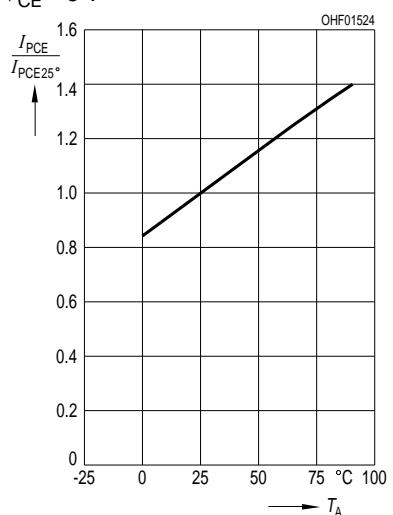
## Capacitance

$C_{\text{CE}} = f(V_{\text{CE}}), f = 1 \text{ MHz}, E = 0$



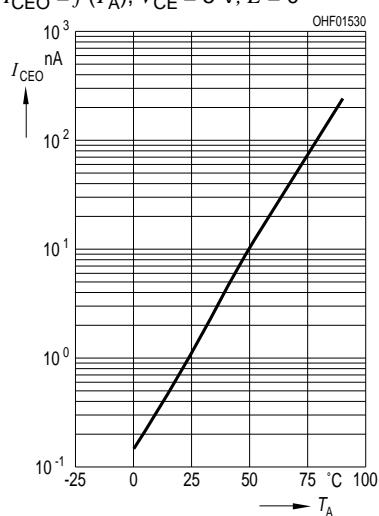
## Photocurrent $I_{\text{PCE}}/I_{\text{PCE}25^\circ} = f(T_A)$ ,

$V_{\text{CE}} = 5 \text{ V}$



## Dark current

$I_{\text{CEO}} = f(T_A), V_{\text{CE}} = 5 \text{ V}, E = 0$



## Photocurrent $I_{\text{PCE}} = f(E_e), V_{\text{CE}} = 5 \text{ V}$

